



Si photodiodes

S2386 series

For visible to near IR, general-purpose photometry

- **Features**
- → High sensitivity in visible to near infrared range
- Low dark current
- High reliability
- Superior linearity

- Applications
- Analytical instruments
- Optical measurement equipment

Structure / Absolute maximum ratings

				Absolute maximum ratings					
Type no.	Dimensional outline/ Window material*	Package	Photosensitive area size	Reverse voltage VR max	Operating temperature Topr	Storage temperature Tstg (°C)			
			(mm)	(V)	(°C)				
S2386-18K	(1)/K	TO-18	1.1 × 1.1						
S2386-18L	(2)/L	10-16	1.1 ^ 1.1			-55 to +125			
S2386-5K	(3)/K		2.4 × 2.4	30	-40 to +100				
S2386-44K	(4)/K	TO-5	3.6 × 3.6	30	-40 10 +100				
S2386-45K	(5)/K		3.9 × 4.6						
S2386-8K	(6)/K	TO-8	5.8 × 5.8						

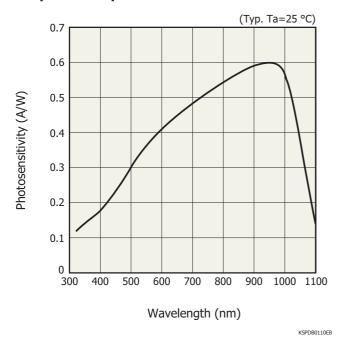
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

■ Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

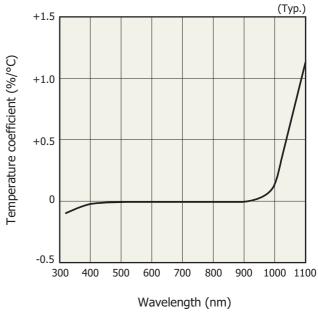
Type no.	Spectral response range	Peak sensitivity wavelength λp	rity ggth λp	S (A/W) GaP He-No		GaAs LED	Short circuit current Isc 100 lx		Dark current ID VR= 10 mV	Temp. coefficient of ID	Rise time tr $V_R=0~V$ RL=1 $k\Omega$	Terminal capacitance Ct VR=0 V f=10 kHz	resist	sh	Noise equivalent power NEP VR=0 V
				560 6	633	930	Min. Typ.	max.			. 20 1412	Min.	Тур.	λ=λρ	
	(nm)	(nm)		nm	nm	nm	(µA)		(pA)	(times/°C)	(µs)	(pF)	$(G\Omega)$		(W/Hz ^{1/2})
S2386-18K	320 to 1100	960	0.6	0.38	0.43	0.59	1	1.3	2	1.12	0.4	140	5	100	6.8 × 10 ⁻¹⁶
S2386-18L							4	5.7					٦		
S2386-5K							4.4	6.0	5		1.8	730	2	50	9.6 × 10 ⁻¹⁶
S2386-44K							9.6	12	20		3.6	1600	0.5	- 25	1.4 × 10 ⁻¹⁵
S2386-45K							12	17	30		5.5 2300	0.3			
S2386-8K							26	33	50		10	4300	0.2	10	2.1 × 10 ⁻¹⁵

^{*} Window material K=borosilicate glass, L=lens type borosilicate glass

Spectral response

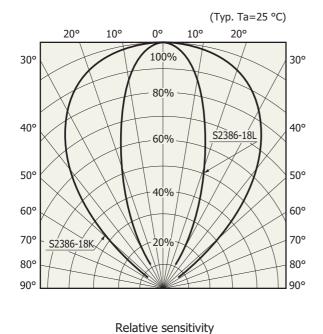


Photosensitivity temperature characteristic



KSPDB0058EC

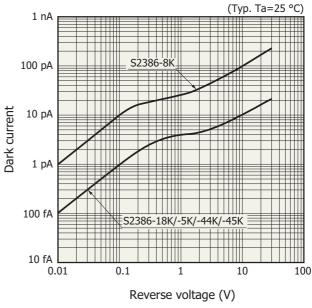
Directivity



leiative sensitivity

KSPDB0111EA

₽ Dark current vs. reverse voltage

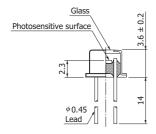


KSPDB0113ED

Dimensional outlines (unit: mm)

(1) S2386-18K

1.1 × 1.1 Note to be a series of the control of th





Distance from photosensitive area center to cap center $-0.3 \le X \le +0.3$ $-0.3 \le Y \le +0.3$

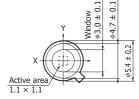
Connected to case

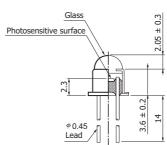
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The glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

KSPDA0191EC

(2) S2386-18L







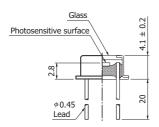


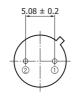
Distance from photosensitive area center to cap center $-0.3 \le X \le +0.3$ $-0.3 \le Y \le +0.3$

KSPDA0048EE

(3) S2386-5K

Photosensitive area 2.4 × 2.4





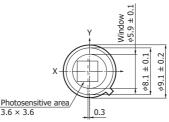
Connected to case

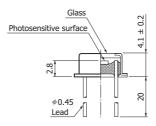
The a m the

Distance from photosensitive area center to cap center -0.3 \(\text{ } \le 4.3 \) -0.3 \(\text{ } \le 4.3 \)

The glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

(4) S2386-44K







area center to cap center $-0.6 \le X \le 0$ $-0.3 \le Y \le +0.3$ The glass window may ex

Connected to case

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The glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

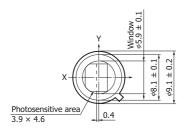
Distance from photosensitive

KSPDA0193EC

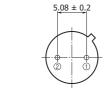


KSPDA0192EC

(5) S2386-45K







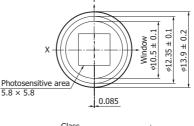
Distance from photosensitive area center to cap center $-0.7 \le X \le +0.1$ $-0.3 \le Y \le +0.3$

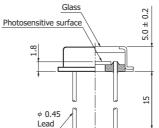
Connected to case

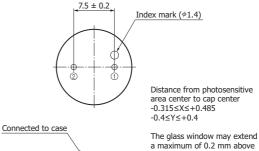
The glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

KSPDA0178ED

(6) S2386-8K







the upper surface of the cap.

KSPDA0194EC

Information described in this material is current as of November, 2013.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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